PERICOM®

PI90LV019
PI90LVB019
PI90LVT019

Single Bus LVDS Transceiver

Features

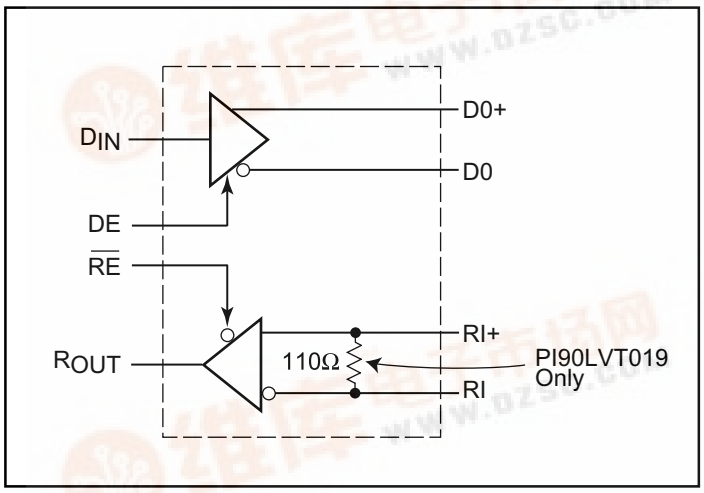
- Bus LVDS Signaling (BLVDS): PI90LVB019
- Designed for double Termination Applications
- Balanced Output Impedance
- Light Bus Loading: 5pF typical
- Glitch-free power up/Down (Driver Disabled)
- High Signaling Rate Capability: >500 Mbps
- Driver:
  – ±350mV Differential Swing into:
  – 100 ohm load (PI90LV019)
  – 50 ohm load (PI90LVB19)
- Receiver:
  – Integrated 110 ohm termination (PI90LVT019 only)
  – Accepts ±50mV (min.) Differential Swing with up to 2.0V ground potential difference
  – Propagation Delay of 3.3ns typ.
  – Low Voltage TTL (LVTTL) Outputs
  – Open, Short, and Terminated Fail Safe
- Bus terminal ESD exceeds 9kV
- Industrial Temperature Operation (–40°C to +85°C)
- Packaging:
  14-lead SOIC (W) and 14-lead TSSOP (L)

Description

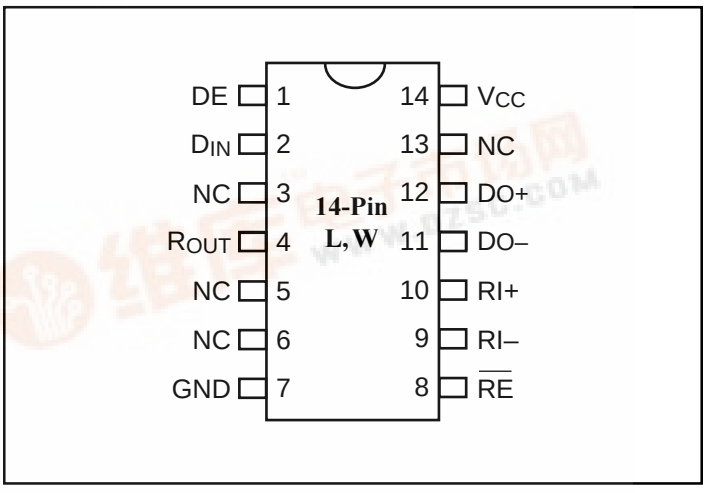
The PI90LVx019 family, differential line drivers and receivers (transceivers), is similar to IEEE1596.3 SCI and ANSI/TIA/EIA-644LVDS standards (the difference is the driver output current is higher). This modification enables true half-duplex operation with more than one LVDS driver or with two line transmission resistors over a 50 ohm differential transmission line. The logic interface provides maximum flexibility resulting from four separate lines that are provided: D_{IN}, DE, $\overline{RE}$, and R_{OUT}. These devices also feature flow through which allows easy PCB routing for short stubs between the bus pins and the connector. The driver has 10mA drive capability, allowing it to drive heavily loaded backplanes, with impedance as low as 27 ohms.

The driver translates between TTL levels (single-ended) to Low Voltage Differential Signaling levels. This allows for high-speed operation, while consuming minimal power with reduced EMI. In addition the differential signaling provides common mode noise rejection of ±1V.

Block Diagram



Pin Configuration



Absolute Maximum Ratings[1,2]

Supply Voltage (V_{CC}) 3.6V
Enable Input Voltage (DE, $\overline{RE}$) ..... –0.3V to (V_{CC} +0.3V)
Driver Input Voltage (DIN) ..... –0.3V to (V_{CC} +0.3V)
Receiver Output Voltage (R_{OUT}) ..... –0.3V to (V_{CC} +0.3V)
Bus Pin Voltage (DO/RI±) ..... –0.3V to +3.9V
Driver Short Circuit ..... Continuous
ESD (HBM 1.5kohms, 100pF) ..... >9kV
Maximum Package Power Dissipation at 20°C
SOIC 1025mW
Derate SOIC Package ..... 8.2mW/°C
Storage Temperature Range ..... –65°C to +150°C
Lead Temperature Range (Soldering, 4s) ..... +260°C

Recommended Operating Conditions

	Min.	Max.	Units
Supply Voltage (V_{CC})	3.0	3.6	V
Receiver Input Voltage	0.0	2.9	V
Operating Free-Air Temperature	–40	+85	°C

Note:
Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Table 1. Functional Mode

Mode Selected	DE	$\overline{RE}$
Driver Mode	H	H
Receiver Mode	L	L
3-State Mode	L	H
Full Duplex Mode	H	L

Table 2. Transmitter Mode

Inputs		Outputs	
DE	DI	DO+	DO–
H	L	L	H
H	H	H	L
H	2 > & > 0.8	X	X
L	X	Z	Z

Table 3. Receiver Mode

Inputs		Outputs
$\overline{RE}$	(RI+) - (RI–)	
L	L (< –100mV)	L
L	H (> +100mV)	H
L	100mV > & > –100mV	X
H	X	Z

Table 4. Device Pin Description

Pin Name	Pin #	Inputs/ Outputs	Description
DIN	2	I	TTL Driver Input
DO±RI±	6,7	I/O	LVDS Driver Outputs/ LVDS Receiver Inputs
R_{OUT}	3	O	TTL Receiver Output
$\overline{RE}$	5	I	Receiver Enable TTL Input (Active Low)
DE	1	I	Driver Enable TTL Input (Active High)
GND	4	NA	Ground
V_{CC}	8	NA	Power Supply

DC Electrical Characteristics[2,3]

T_A = –40°C to +85°C, unless otherwise noted. V_{CC} = 3.3V ±0.3V[2,3]

Symbol	Parameter	Conditions		Pin	Min.	Typ.	Max.	Units
DIFFERNTIAL DRIVER CHARACTERISTICS								
V_{OD}	Output Differential Voltage	R_L = 100 ohms, (LV) Figure 1 RL = 50 ohms, (LVB)		DO+ DO–	250	350	450	mV
ΔV_{OD}	V_{OD} Magnitude Change					6	60	
V_{OS}	Offset Voltage				1	1.25	1.7	V
ΔV_{OS}	Offset Magnitude Change					5	60	mV
I_{OZD}	High Impedance Leakage	V_{OUT} = V_{CC} or GND, DE = 0V			–10	±1	+10	µA
I_{OXD}	Power-Off Leakage	V_{OUT} = 3.6V or GND, V_{CC} = 0V			–10	±1	+10	
I_{OSD}	Output Short Circuit Current	V_{OUT} = 0V, DE = V_{CC}	LV		–10	–6	–4	mA
			LVB		–20		–9	
DIFFERNTIAL RECEIVER CHARACTERISTICS								
V_{OH}	Voltage Output High	V_{ID} = +100mV	I_{OH} = –400µA	R_{OUT}	2.9	3.3		V
		Inputs Open			2.9	3.3		
V_{OL}	Voltage Output Low	I_{OL} = 2.0mA, V_{ID} = –100mV				0.1	0.4	
I_{OS}	Output Short Circuit Current	V_{OUT} = 0V			–75	–34	–20	mA
V_{TH}	Input Threshold High			RI+ RI–			+100	mV
V_{TL}	Input Threshold Low				–100			
I_{IN}	Input Current	V_{IN} = +2.4V, or 0V V_{CC} = 3.6V or 0V			–10	±1	±10	µA
DEVICE CHARACTERISTICS								
V_{IH}	Minimum Input High Voltage			D_{IN}, DE, $\overline{RE}$	2.0		V_{CC}	V
V_{IL}	Minimum Input Low Voltage				GND		0.8	
I_{IH}	Input High Current	V_{IN} = V_{CC} or 2.4V				±1	+10	µA
I_{IL}	Input Low Current	V_{IN} = GND or 0.4V				±1	+10	
V_{CL}	Input Diode Clamp Voltage	I_{CLAMP} = –18mA			–1.5	–0.7		V
I_{CC}	No Load Driver Enabled	D_{IN} = V_{CC} or GND DE = V_{CC} = $\overline{RE}$	LV	V_{CC}		4.0	8.0	mA
			LVB			6.0	19.0	
I_{CCL}	Loaded driver enabled	R_L = 100 ohms (all channels) D_{IN} = V_{CC} or GND (all inputs) DE = V_{CC}, $\overline{RE}$ = GND	LV			20	30	
			LVB			35	45	
I_{CCZ}	No Load driver disabled	D_{IN} = V_{CC} or GND, DE = GND, $\overline{RE}$ = V_{CC}	LV			2.2	8.0	
			LVB			3.0	8.0	
$C_{Doutput}$	Capacitance			DO+, DO–		5		pF
C_{Rinput}	Capacitance			RI+, RI–		5		
R_{TERM}	Termination Input Resistance (PI90LVT019)	D_{IN} = V_{CC} or GND		RI+, RI–	90	110	132	Ω

Notes:

1. "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.
2. All currents into device pins are positive, all currents out of device pins are negative. All voltages are referenced to ground except: V_{OD}, V_{ID}, V_{TH}, and V_{TL}, unless otherwise specified.
3. All typicals are given for V_{CC} = +3.3V and T_A = +25°C unless otherwise stated.

Notes continued on next page...

Notes (continued)**:**

4. ESD Rating: HBM (15kohms, 100pF) > 2.0kV EAT (0 ohm, 200pF) >300V.
5. C_L includes probe and fixture capacitance.
6. Generator waveforms for all tests unless otherwise specified: f = 1MHz, ZO = 50 ohms, tr, tf ≤ 6.0ns (0% - 100%) on control pins and ≤ 1.0ns for RI inputs.
7. The PI90LVT019 is a current mode device and only functions with datasheet specification when a resistive load is appplied between the driver outputs.
8. For receiver disable delays, the switch is set to V_{CC} for t_{PZL}, and t_{PLZ} and to GND for t_{PZH} and t_{PHZ}.

AC Electrical Characteristics

T_A = –40°C to +85°C, V_{CC} = 3.3V ±0.3V(6)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
Driver Timing Requirements						
t_{PHLD}	Differential Propagation Delay High to Low	R_L = 100 ohms (LV) R_L = 50 ohms (LVB) C_L = 10pF (Figures 2 & 3)	2.0	4.0	6.5	ns
t_{PLHD}	Differential Propagation Delay Low to High		1.0	5.6	7.0	
t_{SKD}	Differential Skew $\lvert t_{PHLD} - t_{PLHD} \rvert$			0.4	1.0	
t_{TLH}	Transition Time Low to High		0.2	0.7	3.0	
t_{THL}	Transition Time High to Low		0.2	0.8	3.0	
t_{PHZ}	Disable Time High to Z	R_L = 100 ohms (LV) R_L = 50 ohms (LVB) C_L = 10pF (Figures 2 & 3)	1.5	4.0	8.0	
t_{PLZ}	Disable Time Low to Z		2.5	5.3	9.0	
t_{PZH}	Enable Time Z to High		4.0	6.0	8.0	
t_{PZL}	Enable Time Z to Low		3.5	6.0	8.0	
Receiver Timing Requirements						
t_{PHLD}	Differential Propagation Delay High to Low	C_L = 10pF V_{ID} = 200mV Figures 6 & 7	1.3	2.1	3.0	ns
t_{PLHD}	Differential Propagation Delay Low to High		1.3	2.1	3.0	
t_{SKD}	Differential Skew $\lvert t_{PHLD} - t_{PLHD} \rvert$			0.5	2.0	
t_r	Rise Time			0.8	1.4	
t_f	Fall Time			0.8	1.4	
t_{PHZ}	Disable Time High to Z	R_L = 500 ohms C_L = 10pF Figures 8 & 9	3.0	4.0	6.0	
t_{PLZ}	Disable Time Low to Z		3.0	4.5	6.0	
t_{PZH}	Enable Time Z to High		3.0	6.0	8.0	
t_{PZL}	Enable Time Z to Low		3.0	6.0	8.0	

Test Circuits and Timing Waveforms

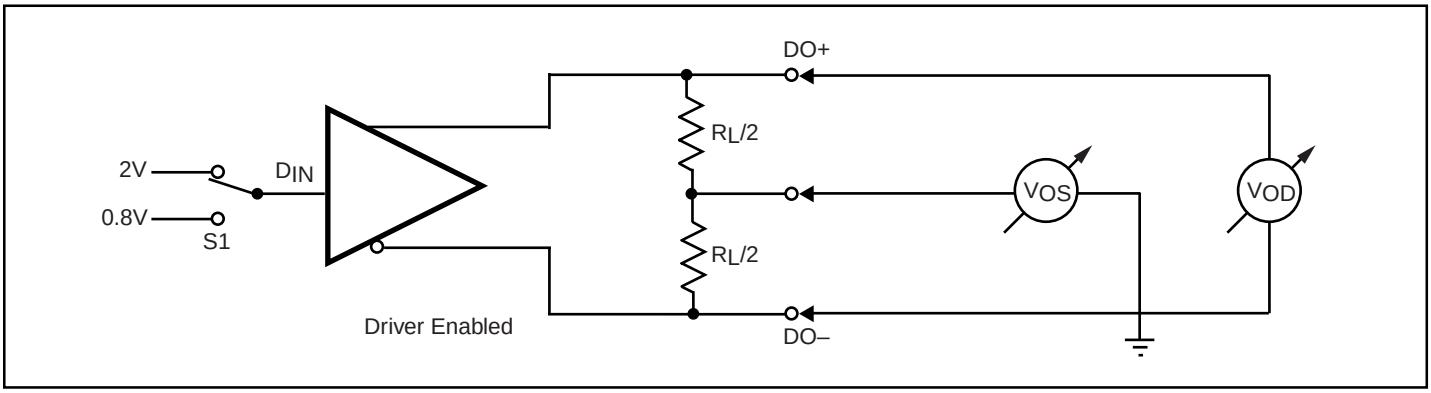


Figure 1. Differential Driver DC Test Circuit

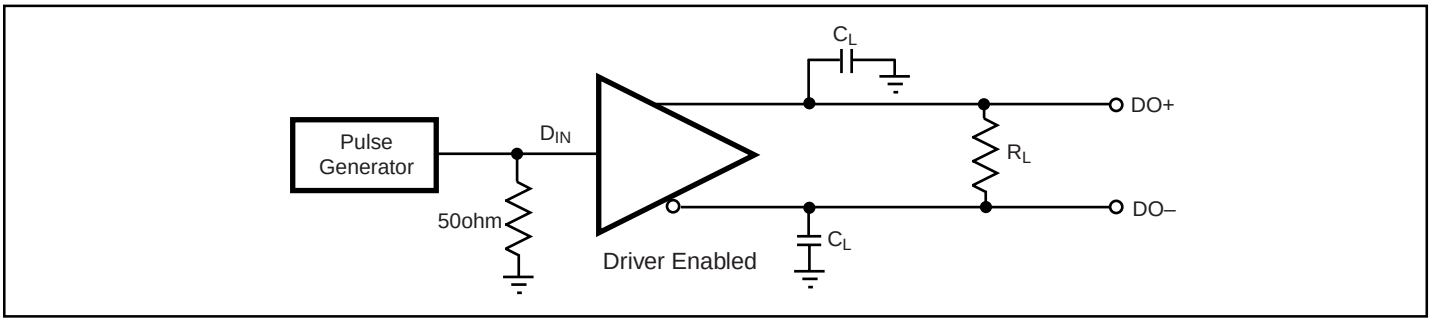


Figure 2. Differential Driver Propagation Delay and Transition Time Test Circuit

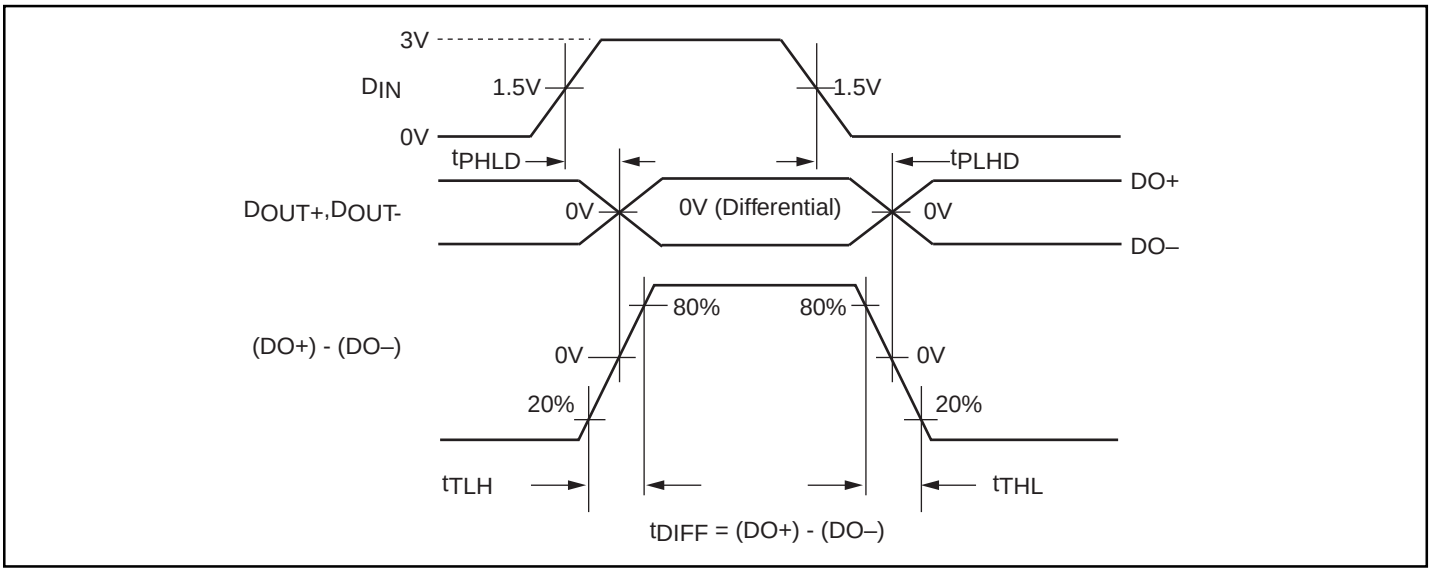


Figure 3. Driver Propagation Delay and Transition Time Waveforms

Test Circuits and Timing Waveforms (continued)

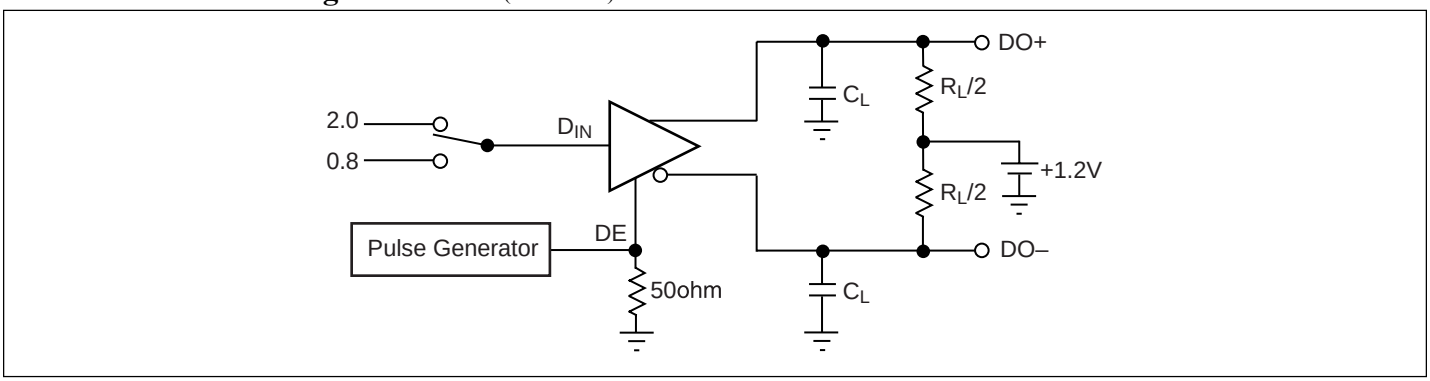


Figure 4. Driver Three-State Delay Test Circuit

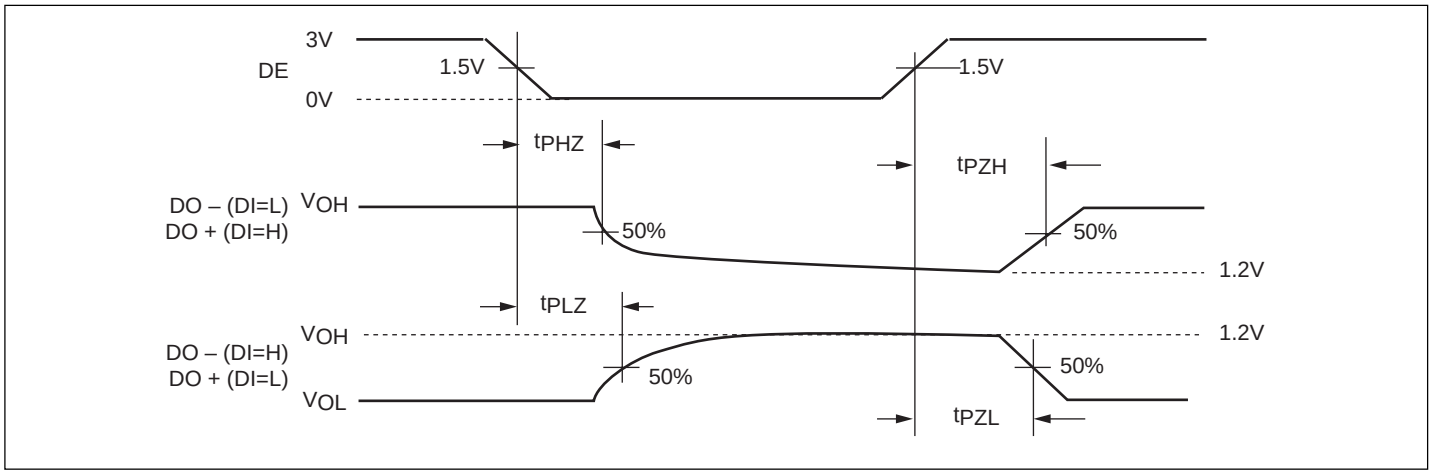


Figure 5. Driver Three-State Delay Waveforms

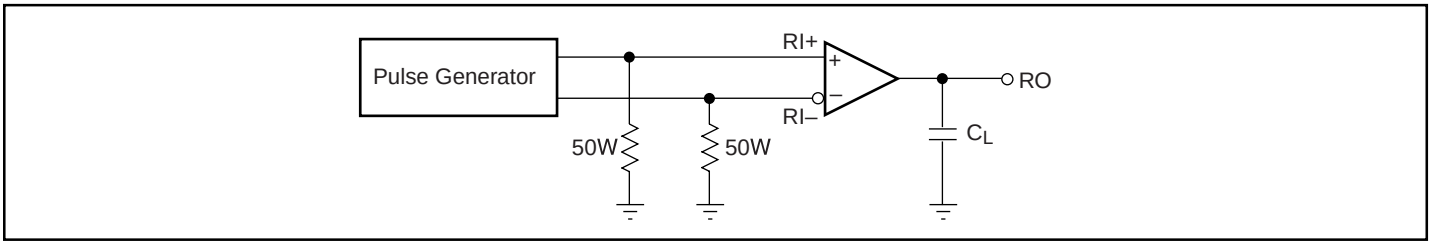


Figure 6. Receiver Propagation Delay and Transistion Time Test Circuit

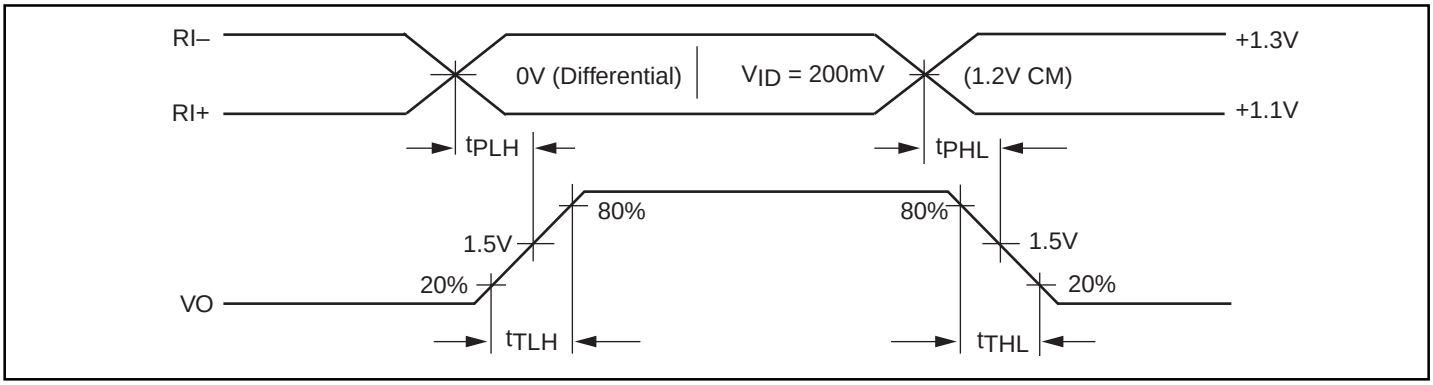


Figure 7. Receiver Propagation Delay and Transistion Time Waveforms

Test Circuits and Timing Waveforms (continued)

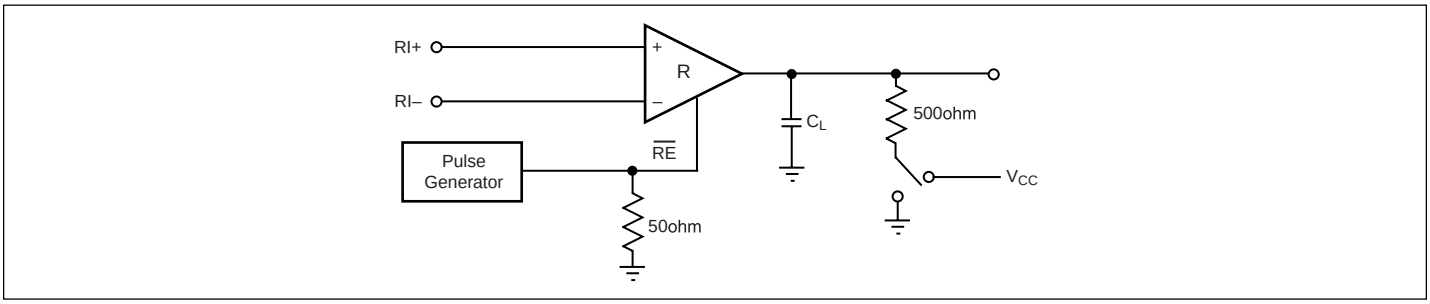


Figure 8. Receiver 3-State Delay Test Circuit

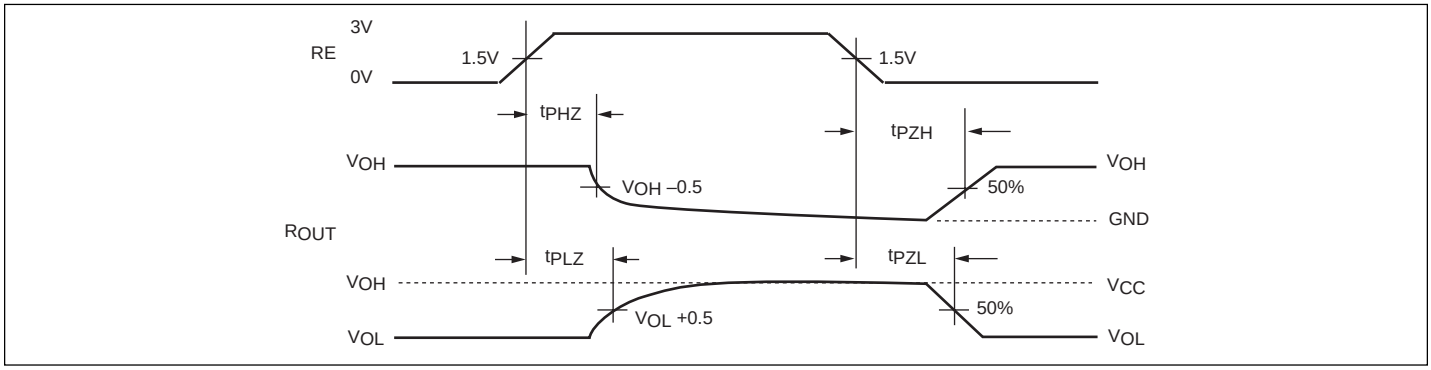


Figure 9. Receiver 3-State Delay Waveforms

Typical Bus Application Configurations

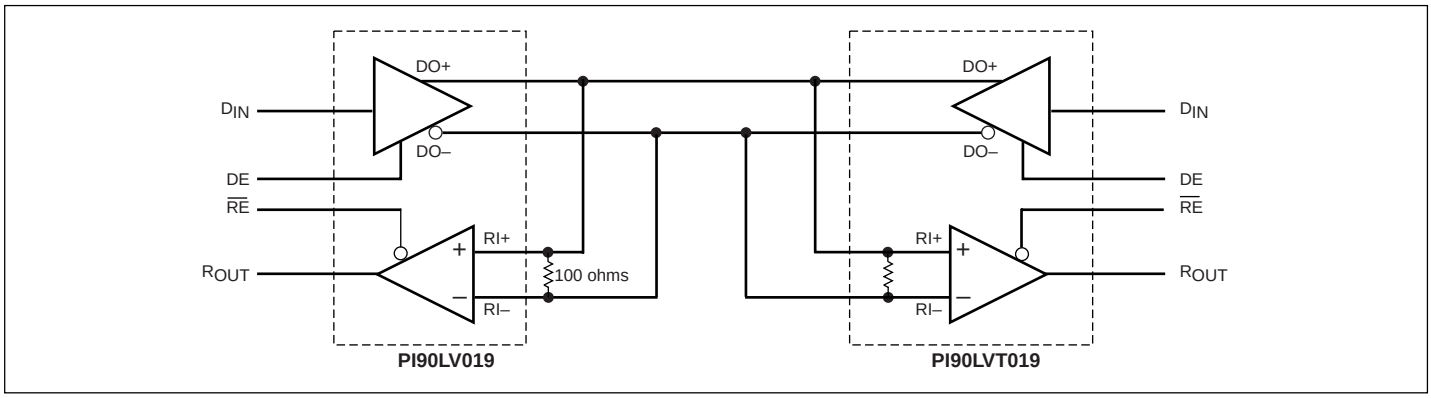


Figure 10. Bidirectional Half-Duplex Point-to-Point Applications

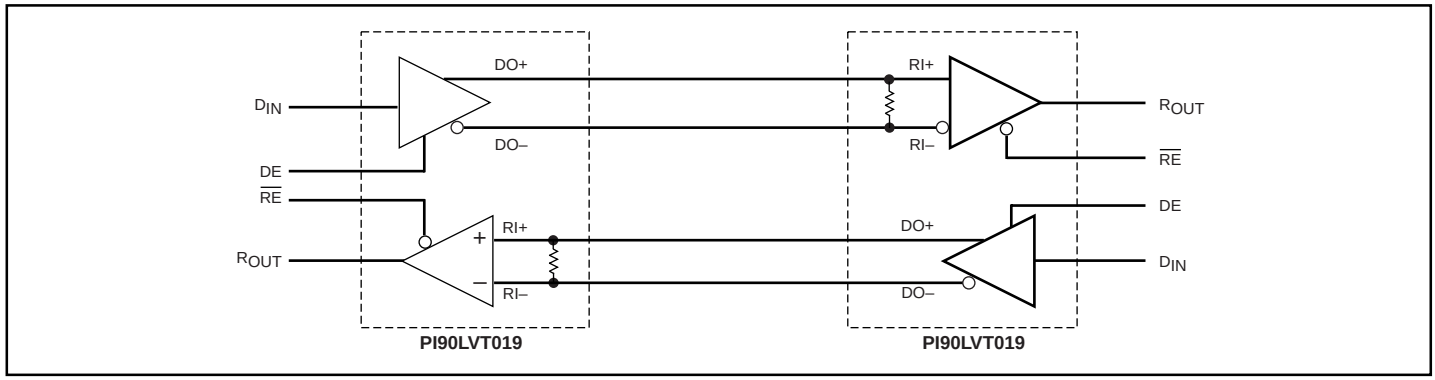
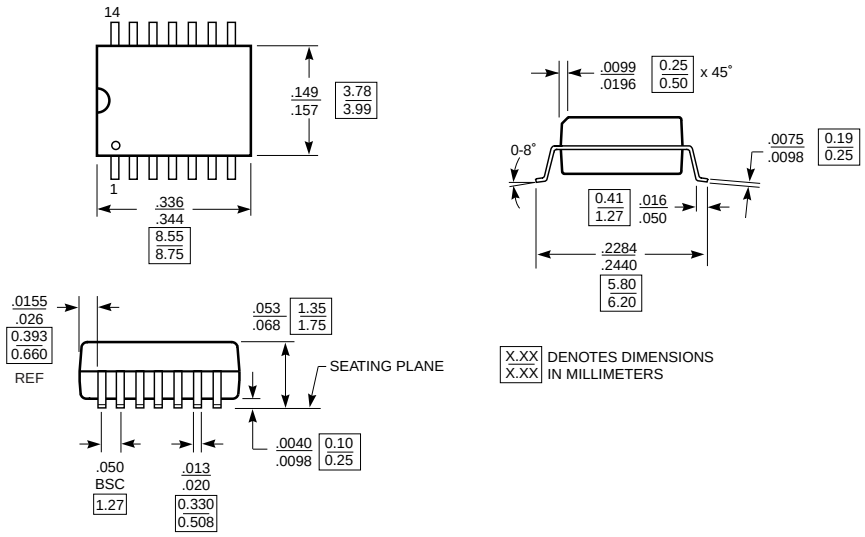
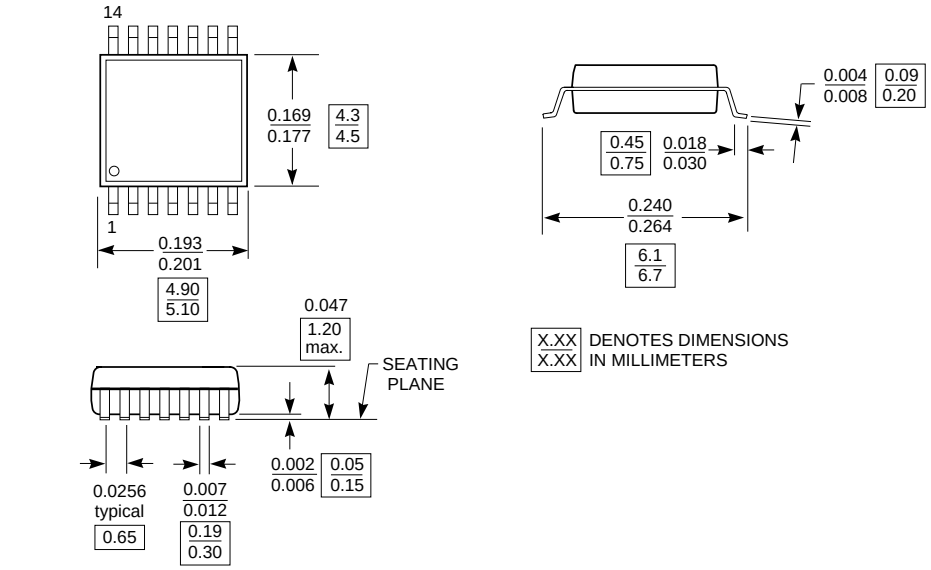


Figure 11. Full-Duplex Point-to-Point Application

14-Pin SOIC Package



14-Pin TSSOP Package



Ordering Information

Part	Pin - Package	Temperature
PI90LV019W	14 - SOIC	–40°C to 85°C
PI90LVT019W	14 - SOIC	–40°C to 85°C
PI90LVB019W	14 - SOIC	–40°C to 85°C
PI90LV019L	14 - TSSOP	–40°C to 85°C
PI90LVT019L	14 - TSSOP	–40°C to 85°C
PI90LVB019L	14 - TSSOP	–40°C to 85°C